NSN 5961-01-298-7957

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-298-7957 **Inclosure Material:** Glass and metal **Overall Length:** 0.320 inches **Terminal Length:** 1.255 inches **Overall Diameter:** 0.225 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 8.8 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 10.00 milliamperes forward current, total rms nanoamperes all semiconductor device diode **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-collector major all semiconductor device diode **Capacitance Rating In Picofarads:** 100.0 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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